

# **Bipolar Transistor**

50 V, 5 A, Low V<sub>CE(sat)</sub>, NPN TO-220-3L

### 2SD1060

#### **Features**

• Low Collector–to–Emitter Saturation Voltage :  $V_{CE(sat)}$  = 0.3 V max /  $I_{C}$  = 3 A,  $I_{B}$  = 0.3 A

#### **Applications**

• Suitable for Relay Drivers, High-Speed Inverters, Converters, and Other General Large-Current Switching

#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V <sub>CBO</sub>	Collector-to-Base Voltage	-	60	٧
V <sub>CEO</sub>	Collector-to-Emitter Voltage	-	50	٧
V <sub>EBO</sub>	Emitter-to-Base Voltage	-	6	V
I <sub>C</sub>	Collector Current	-	5	Α
I <sub>CP</sub>	Collector Current (Pulse)	ı	9	Α
PC	Collector Dissipation	-	1.75	W
		T <sub>C</sub> = 25°C	30	W
Tj	Junction Temperature	-	150	°C
Tstg	Storage Temperature	-	-55 to +150	°C

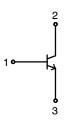
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



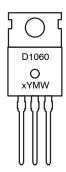
- 1. Base
- 2. Collector
- 3. Emitter

TO-220, 3L CASE 221AU

#### **ELECTRICAL CONNECTION**



#### **MARKING DIAGRAM**



D1060x = Specific Device Code

c = S/F

Y = Year of Production
M = Assembly Operation Month

W = Assembly Operation Mor
W = Work Week Number

#### **ORDERING INFORMATION**

Device	Package	Shipping
2SD1060R-1E	TO-220-3L (Pb-Free)	50 Units / Tube
2SD1060S-1E	TO-220-3L (Pb-Free)	50 Units / Tube

#### 2SD1060

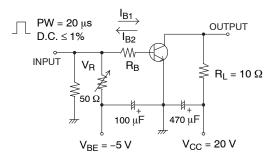
### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C)

Symbol	Parameter	Conditions	Ratings		Unit	
			Min	Тур	Max	
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 40 V, I <sub>E</sub> = 0 A	-	-	0.1	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4 V, I <sub>C</sub> = 0 A	-	_	0.1	mA
h <sub>FE</sub> 1	DC Current Gain	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 A	100*	_	280*	
h <sub>FE</sub> 2		V <sub>CE</sub> = 2 V, I <sub>C</sub> = 2 A	80	_	-	
f <sub>T</sub>	Gain-Bandwidth Product	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	-	30	-	MHz
Cob	Output Capacitance	V <sub>CB</sub> = 10 V, f = 1 MHz	-	100	_	pF
V <sub>CE(sat)</sub>	Collector-to-Emitter Saturation Voltage	I <sub>C</sub> = 3 A, I <sub>B</sub> = 0.3 A	-	_	0.3	V
V <sub>(BR)CBO</sub>	Collector-to-Base Breakdown Voltage	I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0 A	60	_	-	V
V <sub>(BR)CEO</sub>	Collector-to-Emitter Breakdown Voltage	$I_C$ = 1 mA, $R_{BE}$ = $\infty$	50	_	-	V
V <sub>(BR)EBO</sub>	Emitter-to-Base Breakdown Voltage	I <sub>E</sub> = 1 mA, I <sub>C</sub> = 0 A	6	_	-	V
t <sub>on</sub>	Turn-ON Time	See specified Test Circuit	-	0.1	-	μs
t <sub>stg</sub>	Storage Time		-	1.4	-	μs
t <sub>f</sub>	Fall Time		-	0.2	-	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

\* The 2SD1060 is classified by 1 A h<sub>FE</sub> as follows:

Rank	R	s
h <sub>FE</sub>	100 to 200	140 to 280

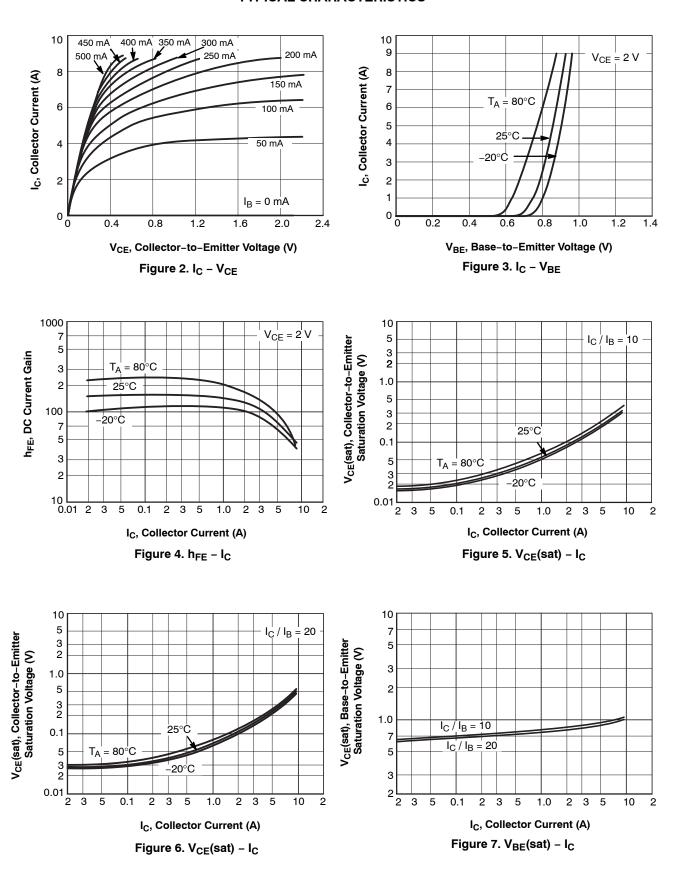


 $I_C = 10I_{B1} = -10I_{B2} = 2 A$ 

Figure 1. Switching Time Test Circuit

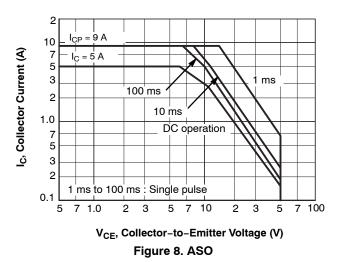
#### 2SD1060

#### **TYPICAL CHARACTERISTICS**



#### 2SD1060

#### TYPICAL CHARACTERISTICS (continued)



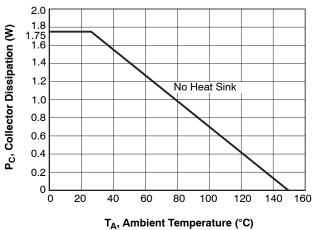
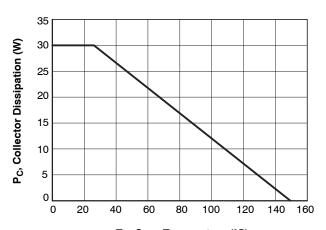


Figure 9. P<sub>C</sub> – T<sub>A</sub>



 $T_C$ , Case Temperature (°C) Figure 10.  $P_C - T_C$ 

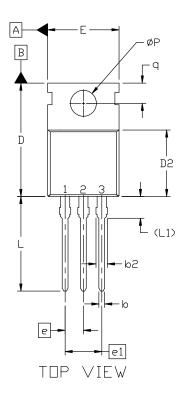


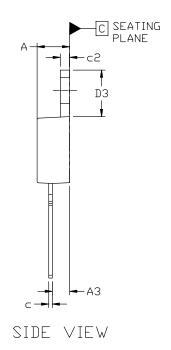


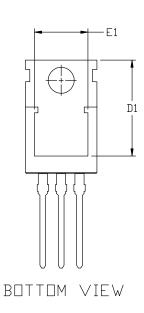


TO-220, 3L, 10.00x9.20x4.50, 2.45P CASE 221AU ISSUE B

**DATE 18 JAN 2024** 







NOTES:

- 1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- 4. MAXIMUM WIDTH FOR F102 DEVICES = 1.37MM.
- 5. DIMENSION "A3" TO BE MEASURED IN THE REGION DEFINED BY L1.

DIM	MILLIMETERS			
ابالط	MIN.	N□M.	MAX.	
Α	4.30	4.50	4.70	
A3	2,20	2.40	2.60	
b	0.70	0.80	0.90	
b2	1.17	1.27	1.37	
<b>C</b>	0.45	0.50	0.60	
<2	1.20	1.30	1.40	
D	15.50	15.70	15.90	
D1	13.10	13.30	13.50	
D2	9.00	9,20	9.40	
D3	6.30	6.50	6.70	
Ε	9,80	10.00	10,20	
E1			8.90	
е	2.54 BSC			
e1	5.08 BSC			
L	12.88	13.08	13.28	
L1	2,80	3.00	3.20	
ØΡ	3.40	3,60	3,80	
q	2.70	2,80	2.90	

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